

## Silicon Bridge Rectifier

$V_{RRM} = 50\text{ V} - 1000\text{ V}$   
 $I_F = 6\text{ A} - 8\text{ A}$

### Features

- Types up to 1000 V  $V_{RRM}$
- Ideal for printed circuit board
- High forward surge current capability
- High temperature soldering guaranteed 250°C/ 10 seconds, 0.375"(9.5 mm) lead length, 5 lbs(2.3 kg) tension
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0

### KBU Package



### Mechanical Data

Case: Molded plastic body  
 Mounting position: Any  
 Terminals: Plated leads, solderable per MIL-STD-750, Method 2026  
 Mounting torque: 5 inch-lbs max  
 Weight: 0.268 oz, 7.6 g

### Maximum ratings, at $T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions	KBU8A	KBU8B	KBU8D	KBU8G	Unit
Repetitive peak reverse voltage	$V_{RRM}$		50	100	200	400	V
RMS reverse voltage	$V_{RMS}$		35	70	140	280	V
DC blocking voltage	$V_{DC}$		50	100	200	400	V
Continuous forward current	$I_F$	$T_C \leq 100\text{ °C}$	8	8	8	8	A
		$T_C \leq 45\text{ °C}$	6	6	6	6	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ °C}$ , $t_p = 8.3\text{ ms}$	300	300	300	300	A
Operating temperature	$T_j$		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	$T_{stg}$		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C

### Electrical characteristics, at $T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions	KBU8A	KBU8B	KBU8D	KBU8G	Unit
Diode forward voltage	$V_F$	$I_F = 8\text{ A}$ , $T_j = 25\text{ °C}$	1	1	1	1	V
Reverse current	$I_R$	$V_R = 50\text{ V}$ , $T_j = 25\text{ °C}$	10	10	10	10	$\mu\text{A}$
		$V_R = 50\text{ V}$ , $T_j = 100\text{ °C}$	500	500	500	500	$\mu\text{A}$

